

#### Single Line Uni-directional Transient Voltage Suppressor

#### **DESCRIPTION**

The GSD7V5HHU TVS diode is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebooks, and PDA's. It offers superior electrical characteristics such as low clamping voltage, low leakage current and high surge capability. It is designed to protect sensitive electronic components which are connected to power lines, from over-stress caused by ESD (Electrostatic Discharge), EFT (Electrical Fast Transients) and Lighting.

The GESD7V5HHU is in a DFN2020-3L package and will protect one unidirectional line. It may be used to provide ESD protection up to  $\pm$  30kV (Contact and air discharge) according to IEC61000-4-2 , and withstand peak pulse current up to 240A (8/20µs) according to IEC61000-4-5.

#### **FEATURES**

♦ Transient protection for high-speed data lines IEC 61000-4-2 (ESD) ±30kV (Contact)

±30kV (Air)

♦ Peak power dissipation: 6000W (8/20µs)

♦ Working voltages: 7.5V

♦Low leakage current

♦Low clamping voltage

♦Ultra-small package (2.0mm×2.0mm×0.5mm)

♦ Solid-state silicon-avalanche technology

#### **MACHANICAL DATA**

♦DFN2020-3L package

♦ Flammability Rating: UL 94V-0

♦ High temperature soldering guaranteed: 260°C/10s

♦ Packaging: Tape and Reel

♦Reel size: 7 inch

#### ORDERING INFORMATION

Device: GSD7V5HHUPackage: DFN2020-3LMarking: T07 003

♦ Material: Halogen free and RoHS compliant

◆Packing: Tape & Reel◆Quantity per reel: 3,000pcs

#### **APPLICATIONS**

♦Power lines

♦ Personal digital assistants (PDA's)

♦Microprocessors based equipment

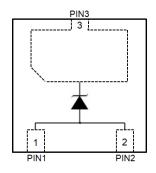
♦Notebooks, Desktops, and Servers

♦ Cell phone Handsets and Accessories

♦Portable Electronics

♦ Peripherals

#### **PIN CONFIGURATION**



#### **PACKAGE OUTLINE**





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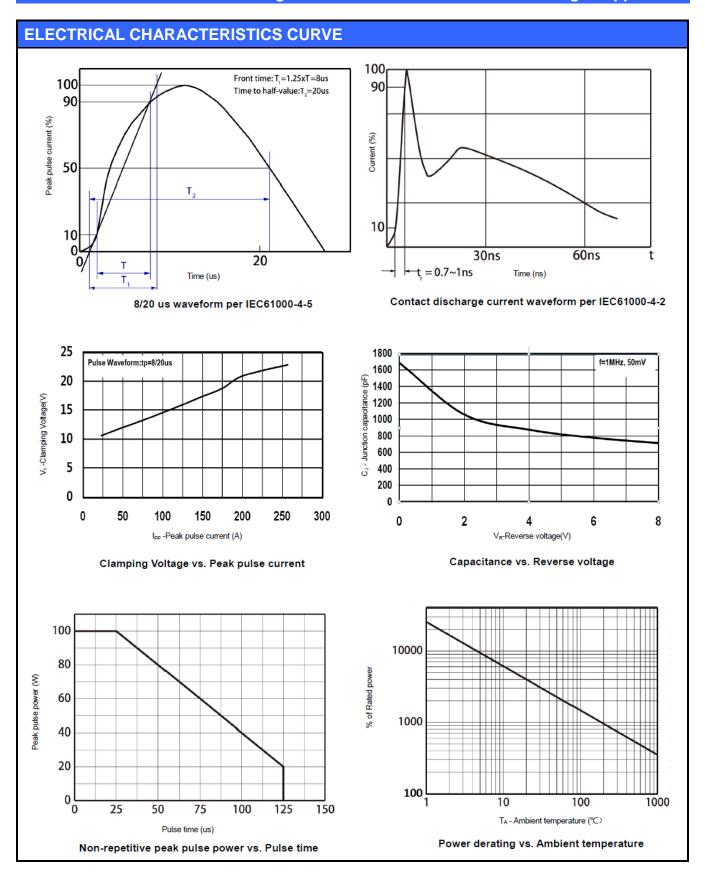
ABSOLUTE MAXIMUM RATING								
Symbol	Parameter	Value	Units					
V <sub>ESD</sub>	ESD per IEC 61000-4-2 (Contact) ESD per IEC 61000-4-2 (Air)	±30 ±30	kV					
P <sub>PP</sub>	Peak Pulse Power (8/20μs)	6000	W					
T <sub>OPT</sub>	Operating Temperature	-55~125	°C					
T <sub>STG</sub>	Storage Temperature	-55~150	°C					
TL	Lead Soldering Temperature	260(10sec)	°C					

ELECTRICAL CHARACTERISTICS (Tamb=25°C)								
Symbol	Parameter	Test Condition	Min	Тур	Max	Units		
V <sub>RWM</sub>	Reverse Working Voltage				7.5	V		
$V_{BR}$	Reverse Breakdown Voltage	I <sub>T</sub> = 1mA	8	9	10	V		
I <sub>R</sub>	Reverse Leakage Current	$V_{RWM} = 7.5V$			1	uA		
I <sub>PP</sub>	Peak Pulse Current	t <sub>p</sub> = 8/20µs			240	А		
V <sub>C</sub>	Clamping Voltage	$I_{PP} = 50A, t_p = 8/20\mu s$		13	15.5	V		
		$I_{PP} = 100A$ , $t_p = 8/20 \mu s$		15.5	18.5	V		
		$I_{PP} = 240A$ , $t_p = 8/20\mu s$		21	25	V		
CJ	Junction Capacitance	$V_R = 0V$ , $f = 1MHz$	1600	1700	2000	pF		

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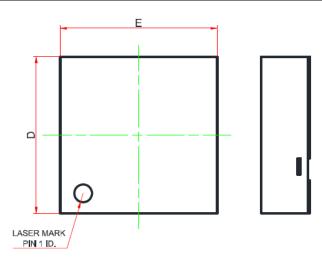
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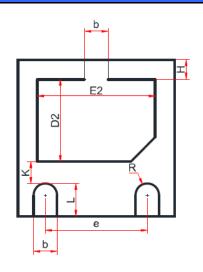


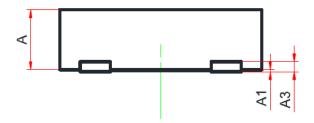


**Single Line Uni-directional Transient Voltage Suppressor** 

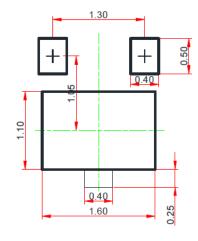
### **DFN2020-3L PACKAGE OUTLINE DIMENSIONS**







### Recommend Land Pattern (Unit: mm)



Symbol	Dimensions In Millimeters				
Symbol	Min.	Тур.	Max.		
Α	0.51	0.55	0.60		
A1	0.00	0.02	0.05		
A3	0.15 REF.				
b	0.25	0.30	0.35		
D	1.90	2.00	2.10		
Е	1.90	2.00	2.10		
D2	0.85	1.00	1.10		
E2	1.35	1.50	1.60		
е	1.20	1.30	1.40		
Н	0.20	0.25	0.30		
K	0.20	0.30	0.40		
L	0.35	0.40	0.45		
R	0.15	-	-		

Note:

This recommended land pattern is for reference purpose only.